

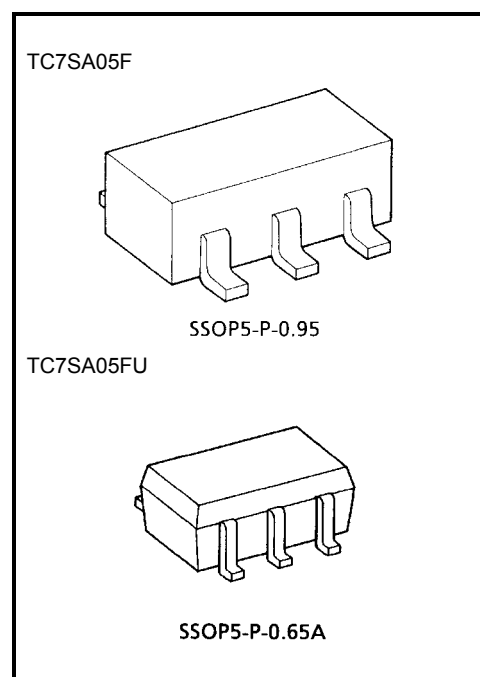
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SA05F, TC7SA05FU

Inverter (open drain) with 3.6 V Tolerant Input and Output

Features

- Low voltage operation : $V_{CC} = 1.8 \sim 3.6 \text{ V}$
- High speed operation : $t_{pd} = 2.8 \text{ ns (max)} (V_{CC} = 3.0 \sim 3.6 \text{ V})$
 $t_{pd} = 3.7 \text{ ns (max)} (V_{CC} = 2.3 \sim 2.7 \text{ V})$
 $t_{pd} = 7.4 \text{ ns (max)} (V_{CC} = 1.8 \text{ V})$
- High Output current : $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$
 $I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$
- Latch-up performance : $\pm 300 \text{ mA}$ or more
- ESD performance : Human body model $> \pm 200 \text{ V}$
Machine model $> \pm 2000 \text{ V}$
- Power down protection is provided on all inputs and outputs.



Weight

SSOP5-P-0.95 : 0.016 g (typ.)

SSOP5-P-0.65A : 0.006 g (typ.)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

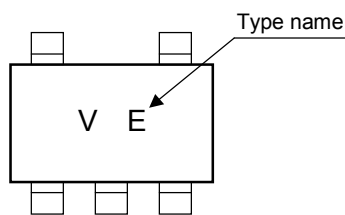
Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	$-0.5 \sim 4.6$	V
DC input voltage	V_{IN}	$-0.5 \sim 4.6$	V
DC output voltage	V_{OUT}	$-0.5 \sim 4.6$ (Note 1)	V
		$-0.5 \sim V_{CC} + 0.5$ (Note 2)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	± 50 (Note 3)	mA
DC output current	I_{OUT}	± 50	mA
Power dissipation	P_D	200	mW
DC V_{CC} /ground current	I_{CC}	± 100	mA
Storage temperature range	T_{stg}	$-65 \sim 150$	$^\circ\text{C}$

Note 1: $V_{CC} = 0 \text{ V}$

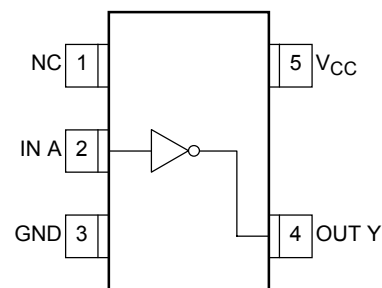
Note 2: High or low state. I_{OUT} absolute maximum rating be observed.

Note 3: $V_{OUT} < \text{GND}$, $V_{OUT} > V_{CC}$

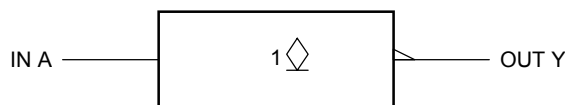
Marking



Pin Assignment (top view)



Logic Diagram



Truth Table

A	Y
L	*H
H	L

*: High impedance

Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input voltage	V_{IN}	-0.3~3.6	V
Output voltage	V_{OUT}	0~3.6 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output current	I_{OH}/I_{OL}	24 (Note 7)	mA
		18 (Note 8)	
		6 (Note 9)	
Operating temperature range	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note 10)	ns/V

Note 4: Data retention only

Note 5: $V_{CC} = 0\text{ V}$

Note 6: High or low state

Note 7: $V_{CC} = 3.0\sim 3.6\text{ V}$

Note 8: $V_{CC} = 2.3\sim 2.7\text{ V}$

Note 9: $V_{CC} = 1.8\text{ V}$

Note 10: $V_{IN} = 0.8\sim 2.0\text{ V}$, $V_{CC} = 3.0\text{ V}$

Electrical Characteristics
DC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$)

Characteristics		Symbol	Test Condition		Min	Max	Unit	
			V _{CC} (V)					
Input voltage	High level	V _{IH}	—		2.7~3.6	2.0	—	V
	Low level	V _{IL}	—		2.7~3.6	—	0.8	
Output voltage	Low level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 100 μA	2.7~3.6	—	0.2	V
				I _{OL} = 12 mA	2.7	—	0.4	
				I _{OL} = 18 mA	3.0	—	0.4	
				I _{OL} = 24 mA	3.0	—	0.55	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V		2.7~3.6	—	±5.0	μA
Power off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.7~3.6	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.7~3.6	—	±20.0	
Increase in I _{CC} per input		ΔI _{CC}	V _{IH} = V _{CC} – 0.6 V		2.7~3.6	—	750	

DC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$)

Characteristics		Symbol	Test Condition		Min	Max	Unit	
				V _{CC} (V)				
Input voltage	High level	V _{IH}	—		2.3~2.7	1.6	—	V
	Low level	V _{IL}	—		2.3~2.7	—	0.7	
Output voltage	Low level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 100 μA	2.3~2.7	—	0.2	V
				I _{OL} = 12 mA	2.3	—	0.4	
				I _{OL} = 18 mA	2.3	—	0.6	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	—	±5.0	μA
Power off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.3~2.7	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.3~2.7	—	±20.0	

DC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$)

Characteristics		Symbol	Test Condition		Min	Max	Unit	
			V _{CC} (V)					
Input voltage	High level	V _{IH}	—		1.8~2.3	0.7 × V _{CC}	—	V
	Low level	V _{IL}	—		1.8~2.3	—	0.2 × V _{CC}	
Output voltage	Low level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 100 μA	1.8	—	0.2	V
				I _{OL} = 6 mA	1.8	—	0.3	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V		1.8	—	±5.0	μA
Power off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		1.8	—	±20.0	

AC Characteristics ($T_a = -40 \sim 85^\circ\text{C}$, input: $t_r = t_f = 2.0\text{ ns}$, $C_L = 30\text{ pF}$, $R_L = 500\text{ }\Omega$)

Characteristics		Symbol	Test Condition		Min	Max	Unit
				$V_{CC}(\text{V})$			
Propagation delay time	t_{pZL}	Figure 1, Figure 2		1.8	1.0	8.2	ns
				2.5 ± 0.2	0.8	4.1	
				3.3 ± 0.3	0.6	3.5	
	t_{pLZ}	Figure 1, Figure 2		1.8	1.0	6.8	ns
				2.5 ± 0.2	0.8	3.8	
				3.3 ± 0.3	0.6	3.5	

For $C_L = 50\text{ pF}$, add approximately 300 ps to the AC maximum specification.

Dynamic Switching Characteristics (Ta = 25°C, input: t_r = t_f = 2.0 ns, C_L = 30 pF)

Characteristics	Symbol	Test Condition		Typ.	Unit
			V _{CC} (V)		
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IN} = 1.8 V, V _{IL} = 0 V (Note 11)	1.8	0.25	ns
		V _{IN} = 2.5 V, V _{IL} = 0 V (Note 11)	2.5	0.6	
		V _{IN} = 3.3 V, V _{IL} = 0 V (Note 11)	3.3	0.8	
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IN} = 1.8 V, V _{IL} = 0 V (Note 11)	1.8	−0.25	ns
		V _{IN} = 2.5 V, V _{IL} = 0 V (Note 11)	2.5	−0.6	
		V _{IN} = 3.3 V, V _{IL} = 0 V (Note 11)	3.3	−0.8	
Quiet output minimum dynamic V _{OH}	V _{OLP}	V _{IN} = 1.8 V, V _{IL} = 0 V (Note 11)	1.8	1.5	ns
		V _{IN} = 2.5 V, V _{IL} = 0 V (Note 11)	2.5	1.9	
		V _{IN} = 3.3 V, V _{IL} = 0 V (Note 11)	3.3	2.2	

Note 11: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		Typ.	Unit
			V _{CC} (V)		
Input capacitance	C _{IN}	—	1.8, 2.5, 3.3		pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note 12)	1.8, 2.5, 3.3		pF

Note 12: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

AC Test Circuit

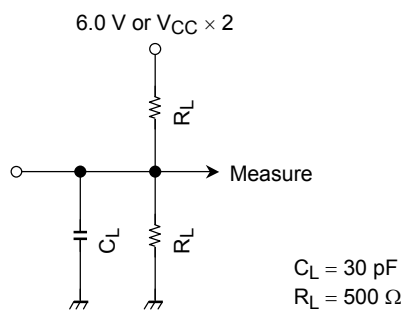
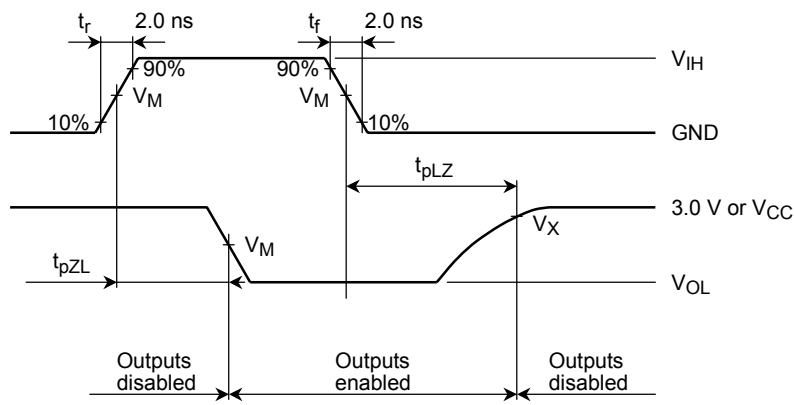


Figure 1

AC Waveform



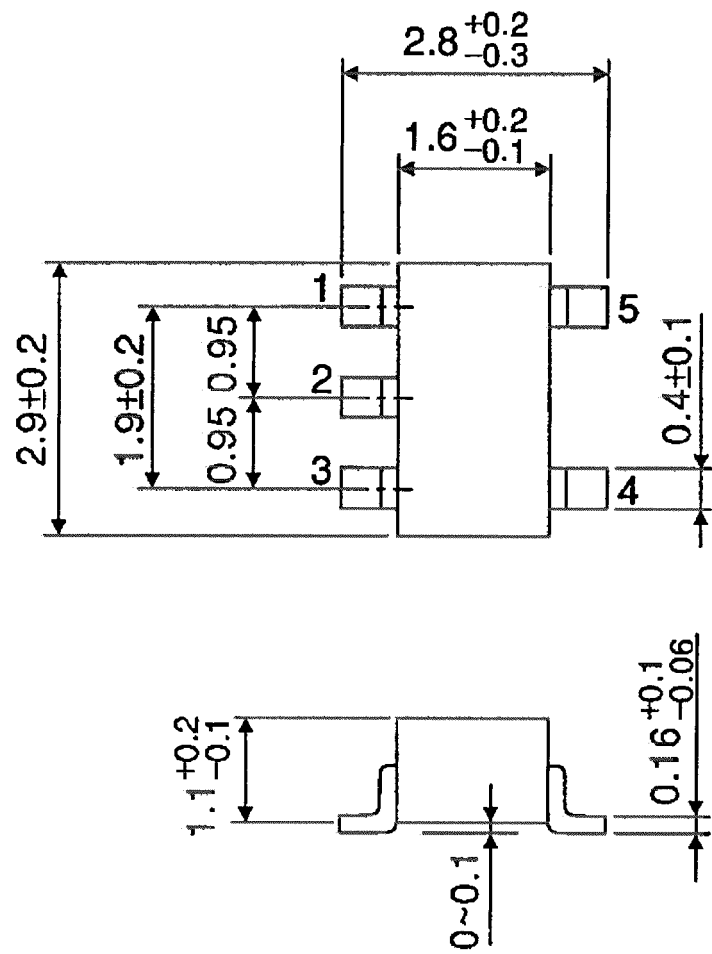
Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

Figure 2 t_{pZL} , t_{pLZ}

Package Dimensions

SSOP5-P-0.95

Unit : mm

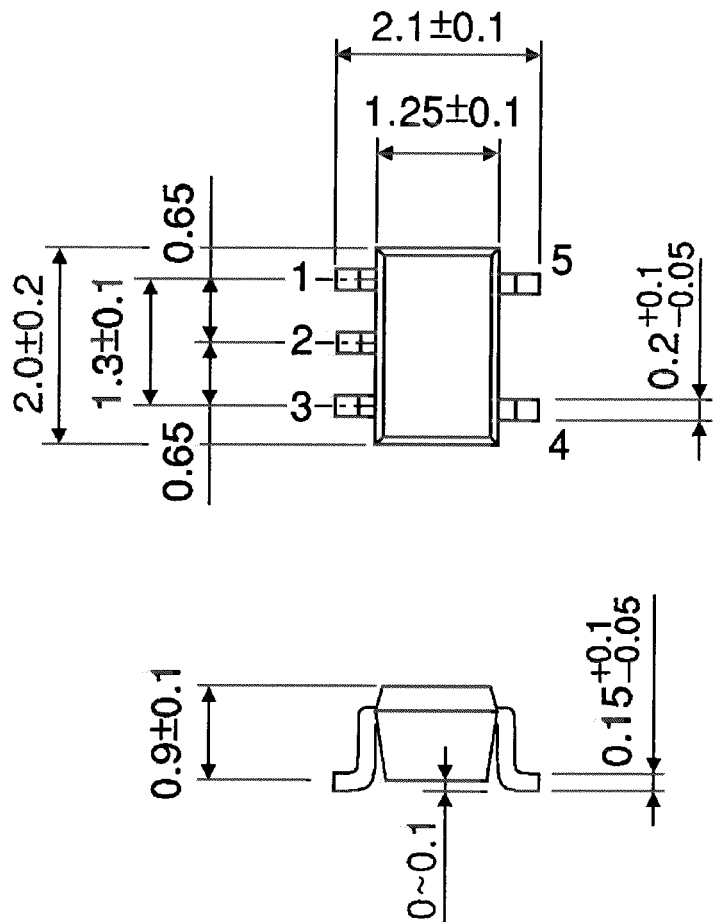


Weight: 0.016 g (typ.)

Package Dimensions

SSOP5-P-0.65A

Unit : mm



Weight: 0.006 g (typ.)

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